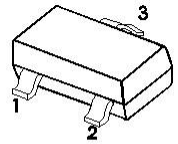
SOT-23



1. BASE
2. EMITTER
3. COLLECTOR

Marking: Y1

特征 Features

- 最大功率耗散 300mW; Power Dissipation of 300mW
- 高稳定性和可靠性; High Stability and High Reliability

机械数据 Mechanical Data

- 封装: SOT-23 封装SOT-23 Small Outline Plastic Package
- 环氧树脂UL 易燃等级Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any

极限值和温度特性(TA = 25℃ 除非另有规定)

Maximum Ratings & Thermal Characteristics (Ratings at 25℃ ambient temperature unless otherwise specified.)

参 数 Parameters	符号Symbol	数值 Value	单位Unit
Collector-Base Voltage	V_{CBO}	40	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter -Base Voltage	V_{EBO}	5	V
Collector Current-Continuous	I_C	1500	mA
Collector Power Dissipation	P_C	300	mW
Junction Temperature	T_j	150	℃
Storage Temperature	Tstg	-55-+150	℃
Thermal resistance From junction to ambient	$R_{\theta JA}$	417	℃/W

电特性 (TA = 25℃ 除非另有规定)

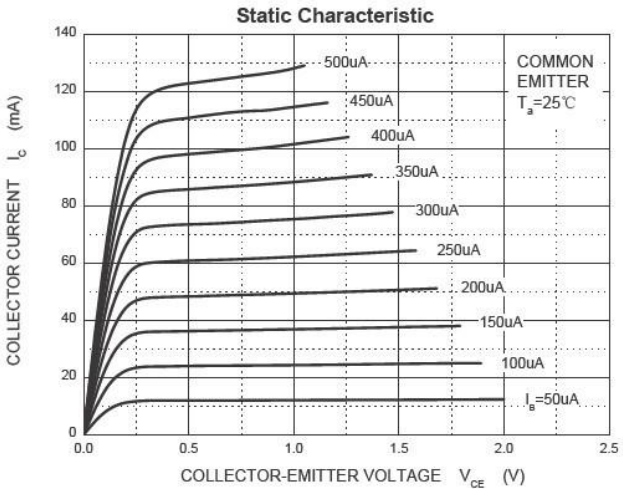
Electrical Characteristics (Ratings at 25℃ ambient temperature unless otherwise specified).

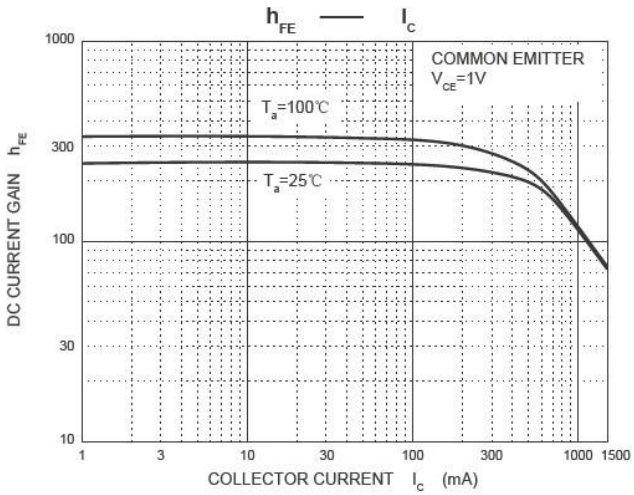
参数 Parameter	符号 Symbols	测试条件 Test Condition	界限 Limits		单位 Unit
			Min	Max	
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C=100uA, I_E=0	40		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	I_C=0.1mA, I_B=0	25		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=100uA, I_C=0	5		V
Collector cut-off current	I_{CEO}	V_{CE}=20V, I_B=0		100	nA
Collector cut-off current	I_{CBO}	V_{CB}=40V, I_E=0		100	nA
Emitter cut-off current	I_{EBO}	V_{EB}=5V, I_C=0		100	nA
DC current gain	$h_{FE(1)}$	V_{CE}=1V, I_C=100mA	120	400	
	$h_{FE(2)}$	V_{CE}=1V, I_C=800mA	40		
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C=800mA, I_B=80mA		0.50	V
Base -emitter saturation voltage	$V_{BE(sat)}$	I_C=800mA, I_B=80mA		1.20	V
Transition frequency	f_T	V_{CE}=10V, I_C=50mA,f=30MHz	100		MHz

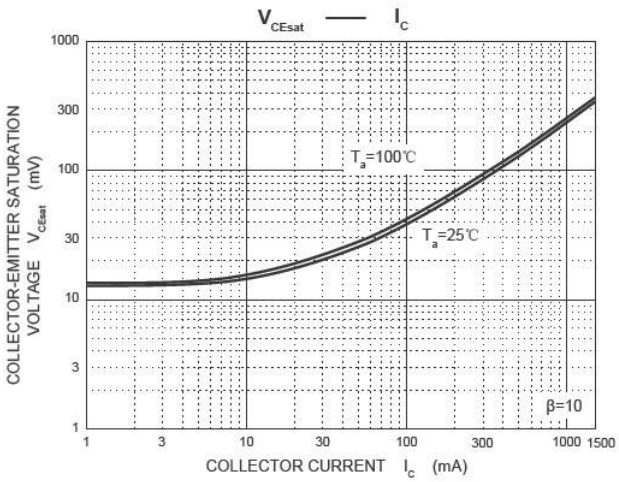
CLASSIFICATION OF $h_{FE(1)}$

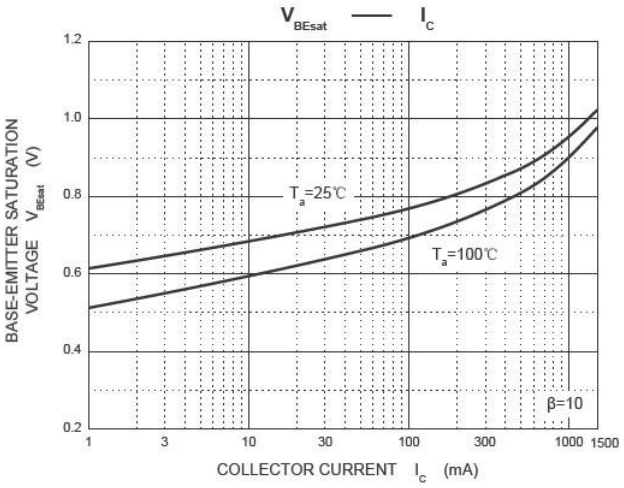
RANK	L	H	J
RANGE	120-200	200-350	300-400

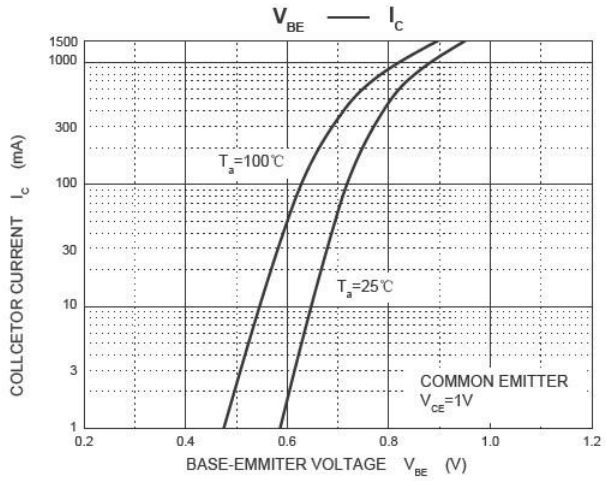
Typical characteristics

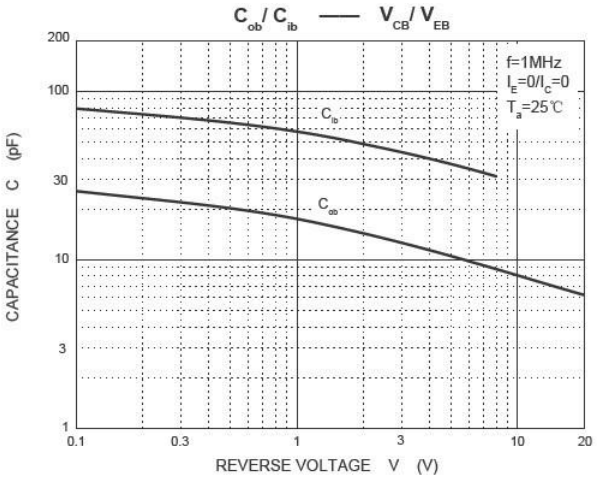


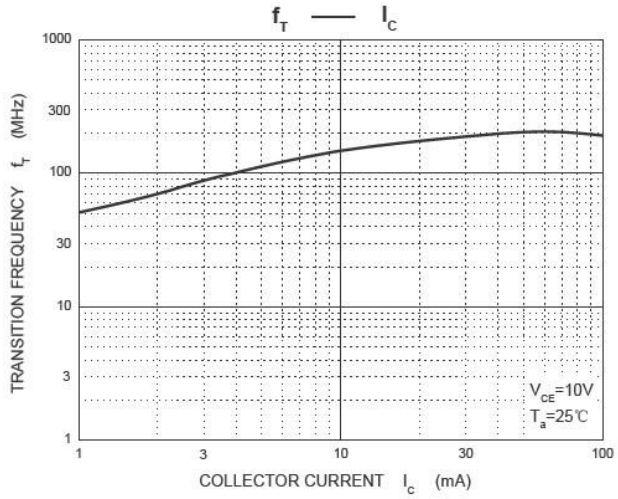


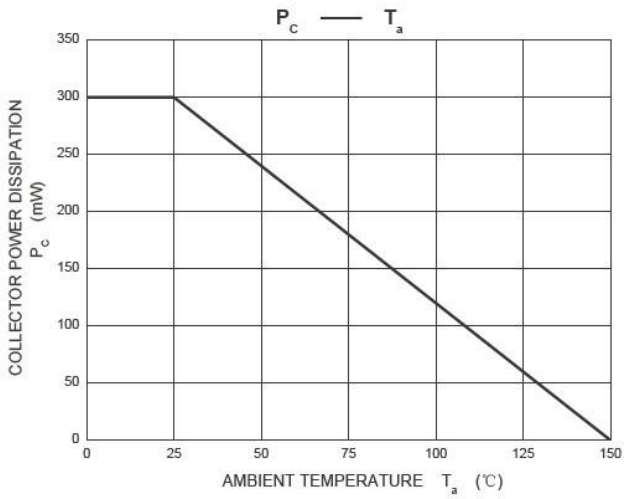




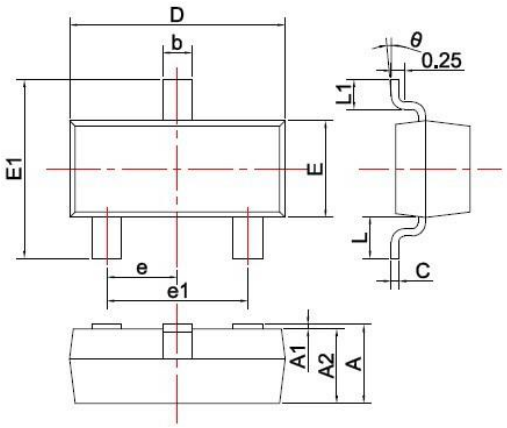








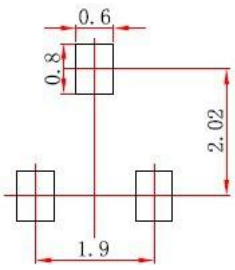
SOT-23 PACKAGE OUTLINE Plastic surface mounted package



SYMBOL	DIMENSIONS	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

Unit: mm

焊盘设计参考Precautions: PCB Design
Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



Note:
1.Controlling dimension:In millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

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